

## 60 V/0.7 Ohm, General Purpose, 1 Form A, Solid State Relay

## Technical Data

#### **Features**

- Compact Solid-State Bidirectional Switch
- Normally-Off Single-Pole Relay Function (1 Form A)
- 60 V Output Withstand Voltage in Both Polarities at 25°C
- 0.75/1.5 Amp Current Ratings (See Schematic for Connections A & B)
- Low Input Current; CMOS Compatibility
- Very Low On-resistance: 0.4  $\Omega$  Typical at 25  $^{\circ}$ C
- ac/dc Signal and Power Switching
- Input-to-Output Momentary Withstand Insulation Voltage: 2500 Vac, 1 Minute
- 16-kV ESD Immunity: MIL-STD-883, Method 3015
- IEEE Surge Withstand Capability (IEEE STD 472-1974)
- CSA Approved
- UL 508 Approved

#### **Applications**

 Programmable Logic Controllers

- Telecommunication Switching Equipment
- Reed Relay Replacement
- 28 Vdc, 24 Vac, 48 Vdc Load Driver
- Industrial Relay Coil Driver

#### **Description**

The HSSR-8060 consists of a high-voltage circuit, optically coupled with a light emitting diode (LED). This device is a solid-state replacement for singlepole, normally-open (1 Form A) electromechanical relays used for general purpose switching of signals and low-power loads. The relay turns on (contact closes) with a minimum input current, I<sub>F</sub>, of 5 mA through the input LED. The relay turns off (contact opens) with an input voltage, V<sub>F</sub>, of 0.8 V or less. The detector contains a high speed photosensitive FET driver circuit and two high voltage MOSFETs.

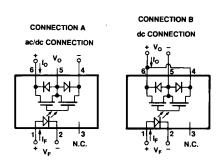
This relay's logic level input control and very low typical output on-resistance of  $0.4~\Omega$  makes it suitable for both ac and dc loads. Connection A, as shown in the schematic, allows the relay to

#### HSSR-8060

switch either ac or dc loads. Connection B, with the polarity and pin configuration as indicated in the schematic, allows the relay to switch dc loads only. The advantage of Connection B is that the on-resistance is significantly reduced, and the output current capability increases by a factor of two.

The electrical and switching characteristics of the HSSR-8060 are specified from -40 $^{\circ}$ C to +85 $^{\circ}$ C.

#### **Functional Diagram**



TRUTH TABLE (POSITIVE LOGIC)						
LED	OUTPUT					
ON	L					
OFF	Н					

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

5965-3575E 1-441

#### **Selection Guide**

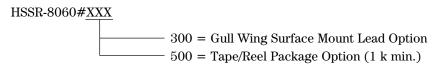
6-Pin DIP (300 Mil) Single Channel	4-Pin DIP (300 Mil) Dual Channel	Maximum Speed t(ON) msec	$\begin{array}{c} \text{Maximum} \\ \text{ON} \\ \text{Resistance} \\ \text{R(ON)} \\ \Omega \\ \end{array}$	Maximum Output Voltage VO(off) V	Maximum Output Current Io(ON) mA	Minimum Input Current	Hermetic 8-Pin Single Channel
Package	Package	25°C	25℃	25℃	25℃	mA	Packages
HSSR-8400 <sup>[1]</sup>		0.95	10	400	150	5	
HSSR-8060		1.4	0.7	60	750	5	
	HSSR-8200 <sup>[1]</sup>	1.5	200	200	40	1	
		6	1	90	800	5	HSSR-7110 <sup>[1]</sup>

#### Note:

1. Technical data are on separate HP publication.

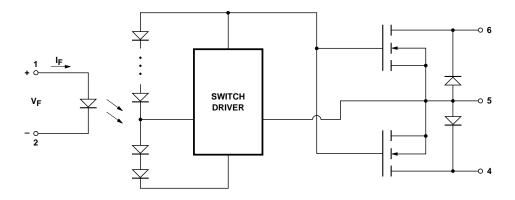
#### **Ordering Information**

Specify part number followed by Option Number (if desired).



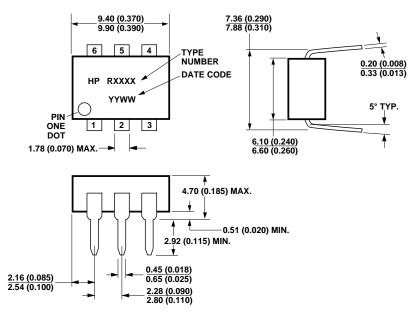
Option data sheets available. Contact your Hewlett-Packard sales representative or authorized distributor for information.

#### **Schematic**



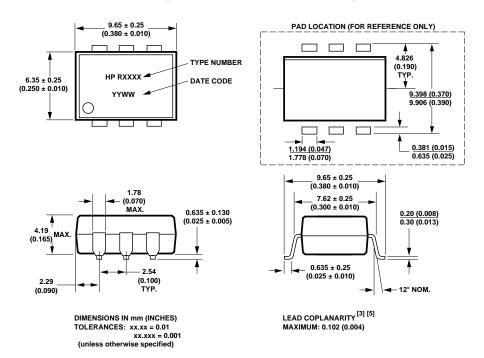
### **Outline Drawing**

6-pin DIP Package (HSSR-8060)



DIMENSIONS IN MILLIMETERS AND (INCHES).

#### 6-Pin Device Outline Drawing Option #300 (Gull Wing Surface Mount)



#### Thermal Profile (Option #300)

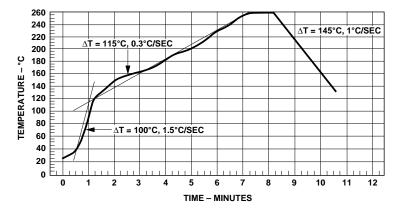


Figure 1. Maximum Solder Reflow Thermal Profile. (Note: Use of non-chlorine activated fluxes is recommended.)

#### **Regulatory Information**

The HSSR-8060 has been approved by the following organizations:

#### $\mathbf{UL}$

Recognized under UL 508, Component Recognition Program, Industrial Control Switches, File E142465.

#### **CSA**

Approved under CAN/CSA-C22.2 No. 14-95, Industrial Control Equipment, File LR 87683.

#### **Insulation and Safety Related Specifications**

Parameter	Symbol	Value	Units	Conditions
Min. External Air Gap (External Clearance)	L(IO1)	7.0	mm	Measured from input terminals to output terminals, shortest distance through air
Min. External Tracking Path (External Creepage)	L(IO2)	8.5	mm	Measured from input terminals to output terminals, shortest distance path along body
Min. Internal Plastic Gap (Internal Clearance)		0.5	mm	Through insulation distance, conductor to conductor, usually the direct distance between the photoemitter and photodetector inside the optocoupler cavity
Tracking Resistance (Comparative Tracking Index)	CTI	200	V	DIN IEC 112/VDE 0303 PART 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

Option 300 – surface mount classification is Class A in accordance with CECC 00802.

#### **Absolute Maximum Ratings**

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Storage Temperature55°C to+125°C
Operating Temperature - $T_A$ 40°C to +85°C
Case Temperature - $T_C$ +105° $C^{[1]}$
Average Input Current - I <sub>F</sub>
Repetitive Peak Input Current - I <sub>F</sub>
(Pulse Width $\leq 1 \text{ ms}$ ; duty cycle $\leq 50\%$ )
Transient Peak Input Current - $I_F$
(Pulse Width $\leq 200 \mu s$ ; duty cycle $\leq 1\%$ )
Reverse Input Voltage - $V_R$
Input Power Dissipation
Output Voltage ( $T_A = 25^{\circ}C$ )
Connection A - $V_0$ 60 to +60 V
Connection B - $V_0$ 0 to +60 V
Average Output Current - Figure 3 ( $T_A = 25^{\circ}C, T_C \le 70^{\circ}C$ )
Connection A - I <sub>0</sub>
Connection B - I <sub>0</sub>
Single Shot Peak Output Current
(100 ms pulse width, $T_A = 25$ °C, $I_F = 10$ mA)
Connection A - I <sub>0</sub>
Connection B - I <sub>0</sub>
Output Power Dissipation
Lead Solder Temperature 260°C for 10 S (1.6 mm below seating plane)
Infrared and Vapor Phase Reflow Temperature
(Option #300) See Fig. 1, Thermal Profile
0 /

#### **Thermal Resistance**

Typical Output MOSFET Junction to Case –  $\theta_{JC}$  = 55°C/W

# Demonstrated ESD Performance

Human Body Model: MIL-STD-883 Method 3015.7 - 16 kV Machine Model: EIAJ 1988.3.28 Version 2), Test Method 20, Condition C – 1200 V

#### Surge Withstand Capability

IEEE STD 472-1974

## **Recommended Operating Conditions**

Parameter	Symbol	Min.	Max.	Units
Input Current (ON)	$I_{F(ON)}$	5	20	mA
Input Voltage (OFF)	$V_{F(OFF)}$	0	0.8	Volt
Operating Temperature	T <sub>A</sub>	-40	+85	°C
Output Voltage				
Connection A	$V_{O(OFF)}$	-55	55	Volt
Connection B		0	55	
Output Current				
Connection A	$I_{O(ON)}$	-0.75	0.75	A
Connection B		-1.5	1.5	

## DC Electrical Specifications

For -40°C  $\leq~T_A \leq~+85^{\circ} C$  unless otherwise specified. All Typicals at  $T_A = 25^{\circ} C.$ 

	Connec-								
Parameter	tion	Sym.	Min.	Typ.	Max.	Units	<b>Test Conditions</b>	Fig.	Notes
Output Withstand Voltage	A	V <sub>O(OFF)</sub>	60 55			V	$\begin{split} V_{F} &= 0.8 \text{ V}, I_{O} = 250  \mu\text{A}, \\ T_{A} &= 25^{\circ}\text{C} \\ V_{F} &= 0.8 \text{ V}, I_{O} = 250  \mu\text{A} \end{split}$	5	
Output On- Resistance	A	R <sub>(ON)</sub>		0.4	0.7	Ω	$I_F = 10 \text{ mA}, I_O = 750 \text{ mA}$ (pulse duration $\leq 30 \text{ ms}$ ),	6,7	3
	В			0.1	0.2		$T_A = 25$ °C		
	A				1.6		$I_F = 10 \text{ mA}, I_O = 750 \text{ mA}$		
	В				0.4		(pulse duration $\leq 30 \text{ ms}$ )		
Output Leakage Current	A	I <sub>O(OFF)</sub>		10-4	1.0	μΑ	$V_{\rm F} = 0.8 \text{ V}, V_{\rm O} = 60 \text{ V},$ $T_{\rm A} = 25^{\circ} {\rm C}$	13	
Output Off- Capacitance	A	C <sub>(OFF)</sub>		135		pF	$V_F = 0.8 \text{ V}, V_O = 25 \text{ V},$ f = 1  MHz	14	
Output Off- set Voltage	A	V <sub>OS</sub>		1		μV	$I_F = 5 \text{ mA}, I_O = 0 \text{ mA}$	18	4
Input Reverse Breakdown Voltage		$V_{ m R}$	3			V	$I_{R} = 100 \mu\text{A}$		
Input Forward Voltage		$V_{ m F}$	1.3	1.6	1.85	V	$I_{\rm F}$ = 10 mA, $T_{\rm A}$ = 25°C	15	
Input Diode Temperature Coefficient		$\Delta V_{\mathrm{F}}/\Delta T_{\mathrm{A}}$		-1.3		mV/°C	$I_{\rm F} = 10 \text{ mA}$		
Input Capacitance		$\mathrm{C_{IN}}$		72		pF	$V_F = 0 V, f = 1 MHz$		

#### **Switching Specifications**

For -40°C  $\leq~T_A \leq~+85^{\circ}\mathrm{C}$  with Connection A, unless otherwise specified. All Typicals at  $T_A = 25^{\circ}\mathrm{C}$ .

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Notes
Turn On Time	$t_{ON}$		0.93	1.4	ms	$I_F = 10 \text{ mA}, V_{DD} = 60 \text{ V},$	2,8,	7
						$I_{\rm O} = 750 \text{ mA}, T_{\rm A} = 25 ^{\circ}\text{C}$	9,10,	
				1.8	ms	$I_{\rm F} = 10 \text{ mA}, V_{\rm DD} = 55 \text{ V},$	20,21	
						$I_O = 750 \text{ mA}$		
Turn Off Time	$t_{ m OFF}$		0.013	0.1	ms	$I_{\rm F} = 10 \text{ mA}, V_{\rm DD} = 60 \text{ V},$	2,8,	
						$I_{\rm O} = 750 \text{ mA}, T_{\rm A} = 25 ^{\circ}\text{C}$	11,12,	
				0.1	ms	$I_F = 10 \text{ mA}, V_{DD} = 55 \text{ V},$	20,21	
						$I_O = 750 \text{ mA}$		
Output	dV <sub>O</sub> /dt	1000			V/µs	$V_{(peak)} = 60 \text{ V}, R_{M} \ge 1 \text{ M}\Omega,$	16	
Transient						$C_{\rm M} = 1000 \ {\rm pF}, T_{\rm A} = 25 {\rm ^{\circ}C}$		
Rejection								
Input-Output	dV <sub>I-O</sub> /dt	2500			V/µs	$V_{DD} = 5 \text{ V}, V_{\text{I-O(peak)}} = 1000 \text{ V},$	17	
Transient						$R_L = 1 \text{ k}\Omega, C_L = 25 \text{ pF},$		
Rejection						$T_A = 25$ °C		

#### **Package Characteristics**

For  $0^{\circ}C \le T_A \le 70^{\circ}C$ , unless otherwise specified. All typicals at  $T_A = 25^{\circ}C$ .

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Symbol	Min.	Тур.	Max.	Units	Test Conditions	Fig.	Notes
$V_{\rm ISO}$	2500			V rms	$RH \le 50\%, t = 1 min, T_A = 25$ °C		5,6
R <sub>I-O</sub>		100		GΩ	$V_{I-O} = 500 \text{ Vdc}, t = 1 \text{ min},$		5
					RH = 45%		
C <sub>I-O</sub>		1.0		pF	$V_{I-O} = 0 \text{ V, f} = 1 \text{ MHz}$		5
	V <sub>ISO</sub>	V <sub>ISO</sub> 2500	V <sub>ISO</sub> 2500  R <sub>I-O</sub> 100	V <sub>ISO</sub> 2500 100	$\begin{array}{c cccc} V_{ISO} & 2500 & & V \ rms \\ \hline R_{I\text{-}O} & 100 & G\Omega \\ \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

<sup>\*</sup>The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the VDE 0884 Insulation Characteristics Table (if applicable), your equipment level safety specification, or HP Application Note 1074, "Optocoupler Input-Output Endurance Voltage."

#### Notes

- 1. The case temperature,  $T_C$ , is measured at the center of the bottom of the package.
- For derating, see Figure 4. The output power P<sub>O</sub> derating curve is obtained when the part is handling the maximum average output current I<sub>O</sub> as shown in Figure 3.
- 3. During the pulsed  $R_{ON}$  measurement ( $I_O$  duration  $\leq$  30 ms), ambient ( $T_A$ ) and case temperature ( $T_C$ ) are equal.
- $\begin{tabular}{ll} 4.\ V_{OS}\ is\ a\ function\ of\ I_F,\ and\ is\ defined\\ between\ pins\ 4\ and\ 6,\ with\ pin\ 4\ as\ the \end{tabular}$
- reference.  $V_{\rm OS}$  must be measured in a stable ambient (free of temperature gradients).
- 5. Device considered a two terminal device: pins 1, 2, and 3 shorted together and pins 4, 5, and 6 shorted together.
- This is a momentary withstand proof test. These parts are 100% tested in production at 3000 V rms, one second.
- 7. For a faster turn-on time, the optional peaking circuit shown in Figure 2 may be implemented.

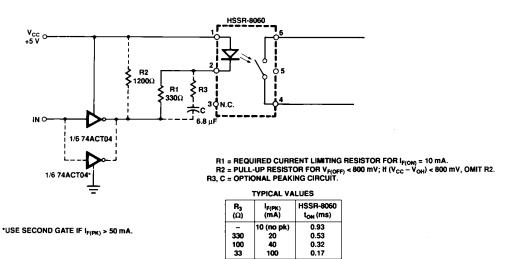


Figure 2. Recommended Input Circuit.

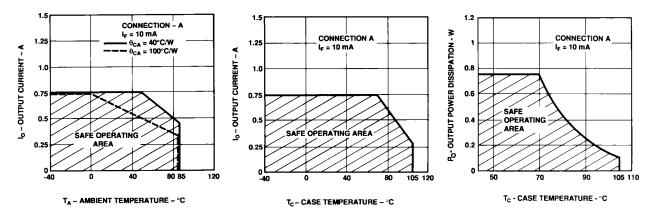


Figure 3A. Maximum Average Output Current Rating vs. Ambient Temperature.

Figure 3B. Maximum Average Output Current Rating vs. Case Temperature.

Figure 4. Output Power Derating vs. Case Temperature.

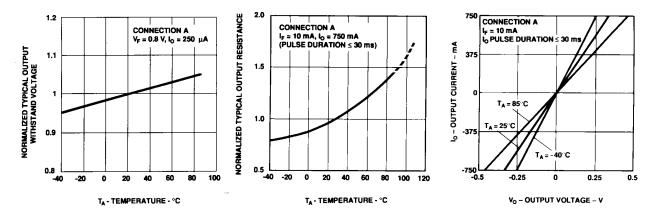


Figure 5. Normalized Typical Output Withstand Voltage vs. Temperature.

Figure 6. Normalized Typical Output Resistance vs. Temperature.

Figure 7. Typical On State Output I-V Characteristics.

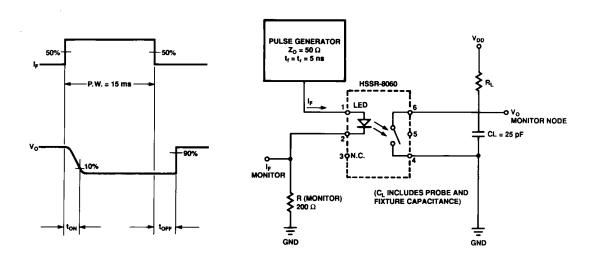


Figure 8. Switching Test Circuit for  $t_{\text{ON}}$ ,  $t_{\text{OFF}}$ .

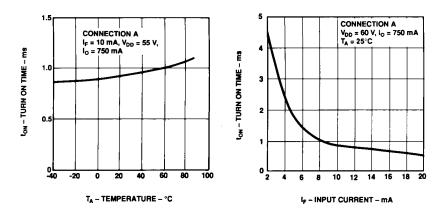


Figure 9. Typical Turn On Time vs. Temperature.

CONNECTION A

tore - TURN OFF TIME - µs

ր∟ -40

-20

= 10 mA, V<sub>DD</sub> = 55 V, I<sub>O</sub> = 750 mA

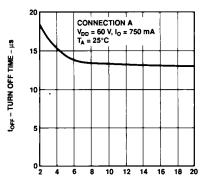


Figure 10. Typical Turn On Time vs.

Input Current.

Figure 11. Typical Turn Off Time vs. Temperature.

20 40 60 80

TA- TEMPERATURE - °C

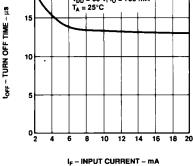
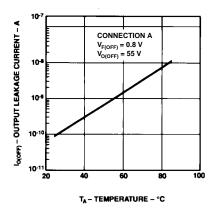
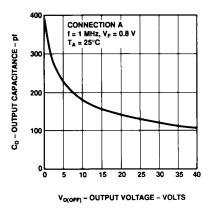


Figure 12. Typical Turn Off Time vs. Input Current.





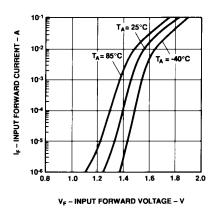


Figure 13. Typical Output Leakage vs. Temperature.

Figure 14. Typical Output Capacitance vs. Output Voltage.

Figure 15. Typical Input Forward Current vs. Input Forward Voltage.

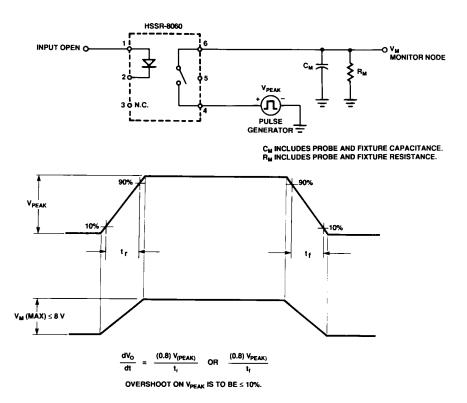


Figure 16. Output Transient Rejection Test Circuit.

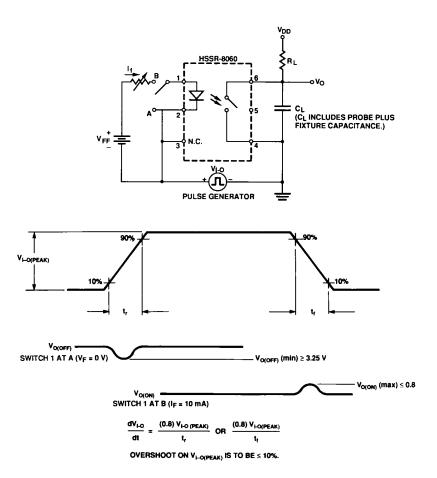


Figure 17. Input-Output Transient Rejection Test Circuit.

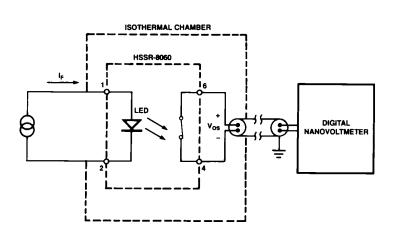
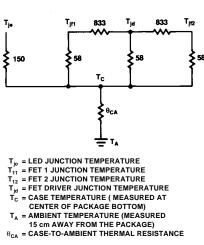
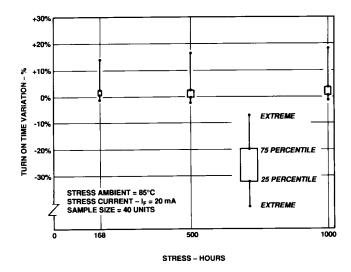


Figure 18. Voltage Offset Test Setup.



ALL THERMAL RESISTANCE VALUES ARE IN  $^{\circ}\text{C/W}.$ 

Figure 19. Thermal Model.



 $\label{thm:condition} \textbf{Figure 20. Turn On Time Variation with High Temperature Operating Life}.$ 

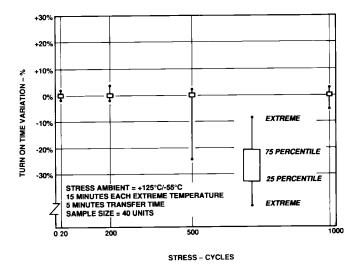


Figure 21. Turn On Time Variation with Temperature Cycling.

# **Applications Information**Thermal Model

The steady state thermal model for the HSSR-8400 is shown in Figure 19. The thermal resistance values given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistances between the LED and other internal nodes are very large in comparison with the other terms and are omitted for simplicity. The components do, however, interact indirectly through  $\theta_{CA}$ , the case-to-ambient thermal resistance. All heat generated flows through  $\theta_{CA}$ , which raises the case temperature  $T_C$  accordingly. The value of  $\theta_{CA}$ depends on the conditions of the board design and is, therefore, determined by the designer.

The typical value for each output MOSFET junction-to-case thermal resistance is specified as 55°C/W. This is the thermal resistance from one MOSFET junction to the case when power is dissipated equally in the MOSFETs. The power dissipation in the FET Driver is negligible in comparison to the MOSFETs.

## **On-Resistance and Derating Curves**

The output on-resistance, R<sub>ON</sub>, specified in this data sheet, is the resistance measured across the output contact when a pulsed current signal ( $I_0 = 150 \text{ mA}$ ) is applied to the output pins. The use of a pulsed signal (≤ 30 ms) implies that each junction temperature is equal to the ambient and case temperatures. The steadystate resistance, R<sub>SS</sub>, on the other hand, is the value of the resistance measured across the output contact when a DC current signal is applied to the output pins for a duration sufficient to reach thermal equilibrium. Rss includes the effects of the temperature rise of each element in the thermal model.

Derating curves are shown in Figures 3 and 4. Figure 3 specifies the maximum average output current allowable for a given ambient or case temperature. Figure 4 specifies the output power dissipation allowable for a given case temperature. Above a case temperature of 93°C, the maximum allowable output current and power dissipation are

related by the expression  $R_{SS} = P_0(\text{max})/(I_0(\text{max}))^2 \text{ from}$  which  $R_{SS}$  can be calculated. Staying within the safe area assures that the steady state junction temperatures remain less than  $125^{\circ}\text{C}$ . As an example, for a case temperature of  $100^{\circ}\text{C}$ , Figure 4 shows that the output power dissipation should be limited to less than 0.5 watts. A check with Figure 3B shows that the output current should be limited to less than 150 mA. This yields an  $R_{SS}$  of  $22~\Omega$ .

#### **Turn On Time Variation**

For applications which are sensitive to turn on time, the designer should refer to Figures 20 and 21. These figures show that although there is very little variation in  $t_{\rm ON}$  within most of the population, a portion of the distribution will vary with use. The optional peaking circuit shown in Figure 2 can be used to reduce the total turn on time and, consequently, any associated variation.